Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
3.078 inches
Overall Diameter:
1.100 inches
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-9
Electrode Internally-electrically Connected To Case:
Cathode
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
1.250 inches
Thread Size:
0.750 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
200.0 reverse voltage, peak
Current Rating Per Characteristic:
250.00 amperes forward current, average absolute
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius case
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 1 insulated wire lead
Specification Data:
80131-release3925 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0